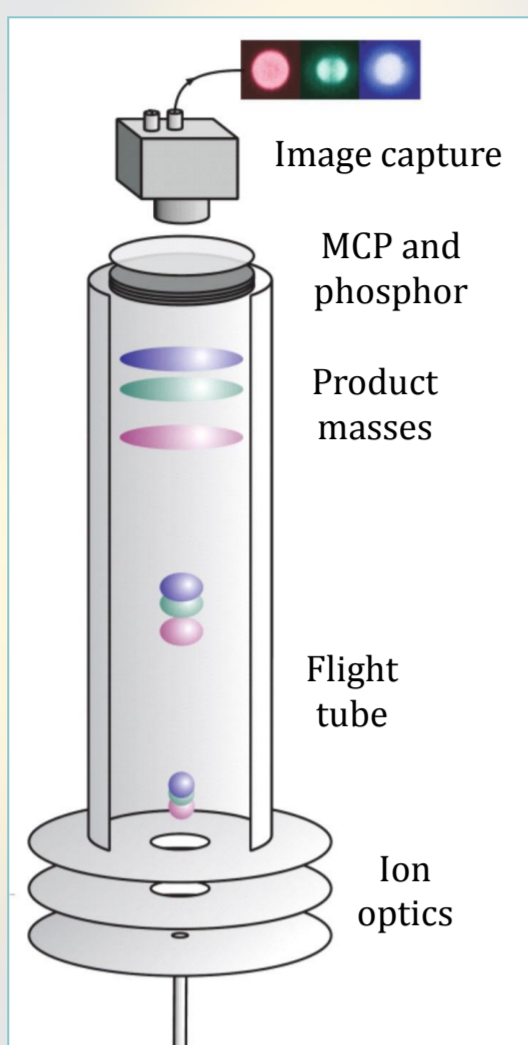


## Pixel Imaging Mass Spectrometry



Pixel Imaging Mass Spectrometry (PI<sub>m</sub>MS) is a combination of traditional Time of Flight (ToF) mass spectrometry and ion imaging.

- Molecular samples are dissociated into ions by laser, these are accelerated into and drift along a flight tube using a tunable electric field.
- The ions are incident on a microchannel plate (MCP) converting them to an electron signal, this is coupled to a phosphor screen converting the electrons to a photon signal, which is recorded by the PI<sub>m</sub>MS camera.
- Compared to traditional ToF mass spectrometers, the PI<sub>m</sub>MS pixel array provides timestamped arrival times with (x,y) co-ordinate information.

Velocity-map imaging time-of-flight mass spectrometer – C. Vallance

- Light ions drift faster than heavy ions and so arrive earlier. This mass dependence on drift time gives a 1-D mass spectrum, integrated across the whole sensor, of dissociated fragments dependent on their time-of-arrival.
- Velocity mapping preserves initial velocities of ions, for studies of reaction dynamics among others. Spatial mapping preserves the initial positions of ions, useful for surface imaging, among others.

M. Brouard et al *Rev. Sci Instrum.* **79** (2008) 123115.

## Sensor Specifications

| Specification        | PI <sub>m</sub> MS 1                        | PI <sub>m</sub> MS 2                     |
|----------------------|---|--|
| Array size           | 72 x 72 pixels                              | 324 x 324 pixels                         |
| Active area          | 5mm x 5mm                                   | 22.7mm x 22.7mm                          |
| Sensor size          | 7mm x 7mm                                   | 25.4mm x 26.1mm                          |
| Pixel size           | 70µm x 70µm                                 |  |
| Pixel threshold trim | 4 trim bits + 1 masking bit per pixel       |  |
| Timestamp storage    | Four 12-bit registers per pixel             |  |
| Test pixel           | 1 test pixel to access inner analogue nodes |  |
| Time resolution      | Target: 25ns<br>Verified: 12.5ns            | Target: 25ns<br>Verification in progress |
| Substrate            | 5µm epi                                     |  |
| Acquisition rate     | 555Hz                                       | 50Hz                                     |

- Extendable 51µs experimental cycle
- < 500 ns dead time within a pixel after a hit
- USB 2.0 digital and analogue readout
- External and internal TTL trigger enabled

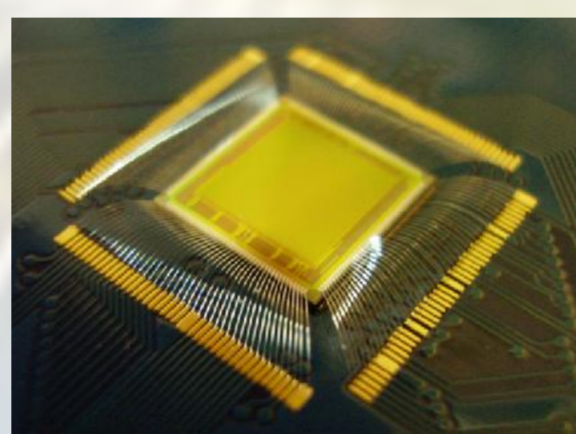
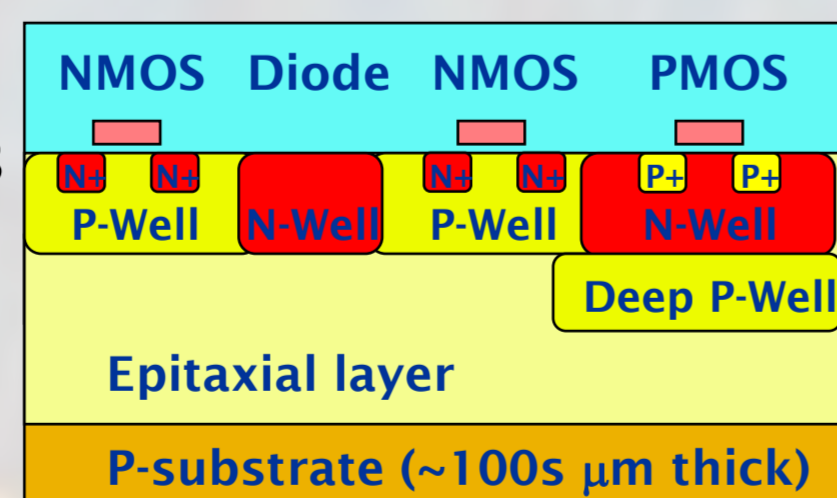


Photo of the PI<sub>m</sub>MS 1 sensor

## Sensor Technology

PI<sub>m</sub>MS is a Monolithic Active Pixel Sensor (MAPS) implemented using 0.18 micron CMOS technology.

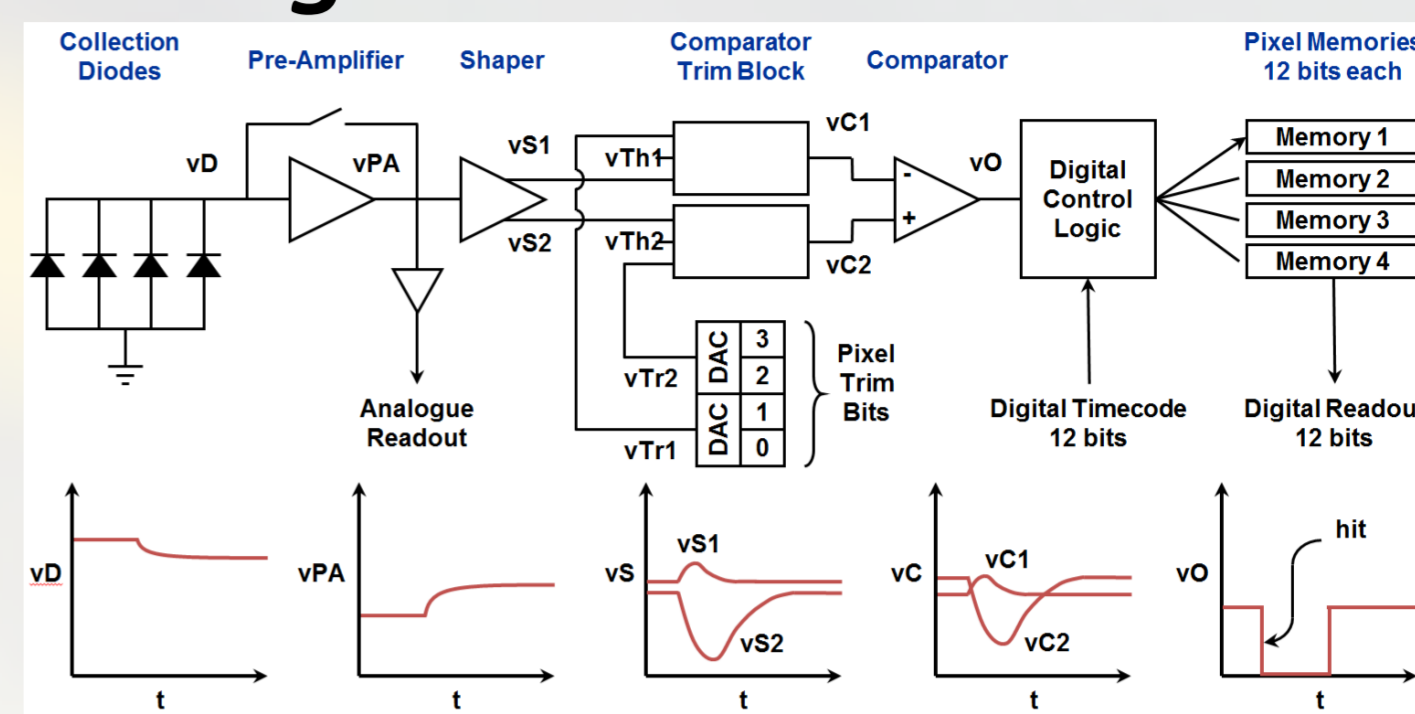
In-pixel circuitry implemented using the INMAPS process developed by STFC-RAL CMOS Sensors Group.



Silicon cross-section, INMAPS – R. Turchetta

- Key advantage: can implement full CMOS circuitry with 100% fill factor.
- This allows for complex in-pixel circuitry and processing. There are a total of 615 transistors in the PI<sub>m</sub>MS1 pixel resulting in over 3 million in the whole chip.
- This is enabled by the deep p-well implant that shields PMOS transistors against the N-wells forming parasitic charge collecting diodes.

## Pixel Design

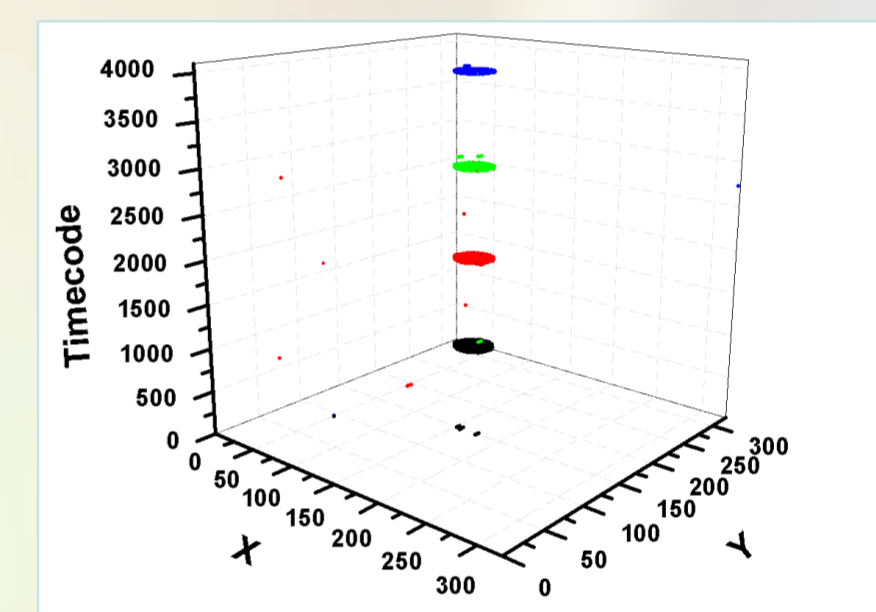
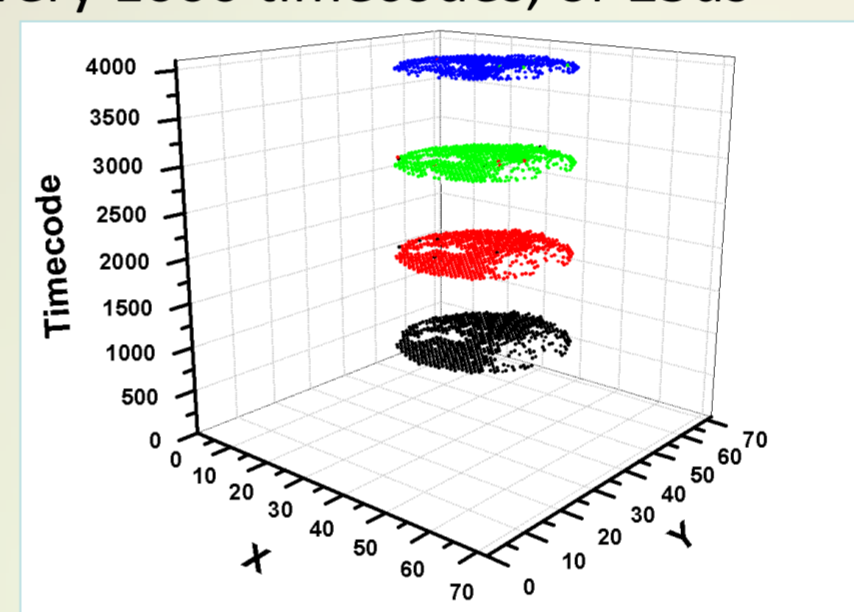


PI<sub>m</sub>MS pixel and signal schematics – JJ John

- Signal charge is collected by 4 diodes in each pixel and amplified.
- A pre-shaper converts steps in charge to pulses.
- A comparator discerns events above a tunable threshold and registers a 'hit' by storing the timecode of the comparator input crossing points.
- Up to 4 time-stamps can be recorded in each pixel per acquisition cycle.
- The pre-amplifier analogue signal is output for intensity information.
- Per pixel capacitor trimming to the comparator inputs corrects for CMOS process variations that cause spread in the threshold levels of a pixel.

## First Results

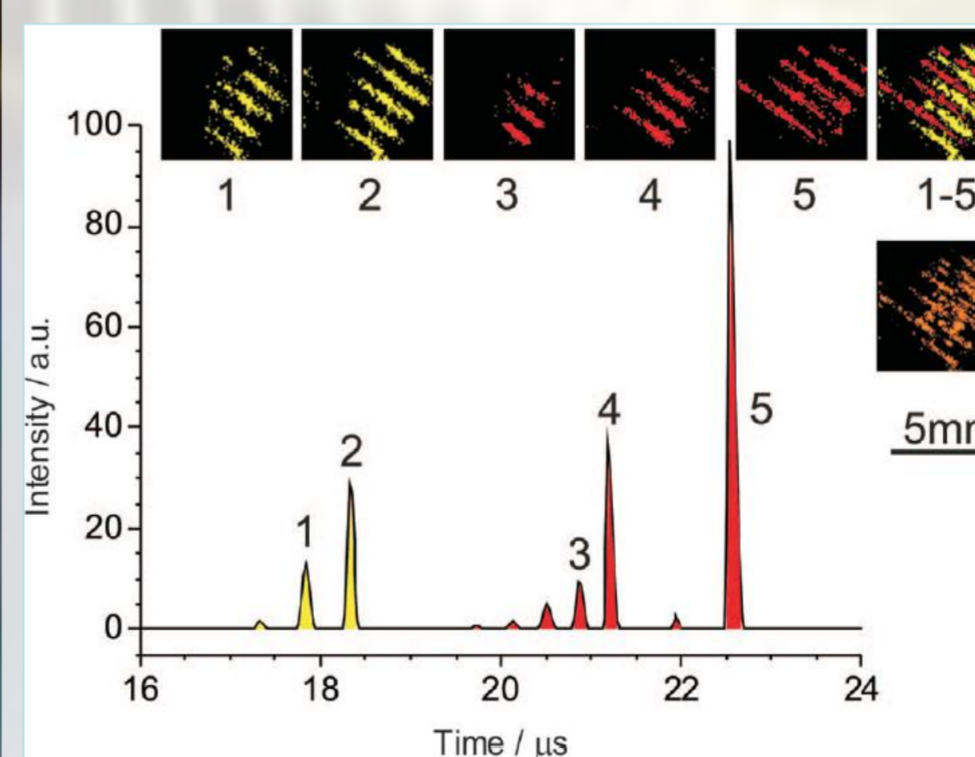
- Initial commissioning tests were performed using a 405nm laser emitting 5ns pulses at a repetition rate of 40 kHz. With the PI<sub>m</sub>MS timecode clock set to increment every 25ns, laser pulses were detected by the sensor every 1000 timecodes, or 25µs



4D Hit map of 4 laser pulses recorded into 4 separate memory registers. Left: PI<sub>m</sub>MS 1, Right: PI<sub>m</sub>MS 2 – L Hill

- PI<sub>m</sub>MS 1 optical characterisation results are shown in the adjacent table – A Clark, I Sedgwick
- The sensitivity calibration using the trimming technique described above has yielded a 9.2mV improvement in threshold spread across the sensor. This will be improved further on PI<sub>m</sub>MS 2 with additional handles on the trim – J Lee

| Characteristic       | Value                         |
|----------------------|-------------------------------|
| Full Well Capacity   | 24,000 e <sup>-</sup>         |
| Fill Factor          | 16.9 %                        |
| Gain                 | 0.2015 DN/e <sup>-</sup>      |
| Quantum Efficiency   | 8-9 %                         |
| Threshold Dispersion | 12.8 mV raw<br>3.6 mV trimmed |



Auramine O (yellow, 1,2) and Rhodamine 590 (red, 3-5) PI<sub>m</sub>MS 1 Mass Spectrum and Ion Images – M. Brouard et al. *Rev. Sci Instrum.* **83** (2012) 114101

Mass spectrum and ion images obtained using PI<sub>m</sub>MS; signals 1 and 2 are contributions from Auramine O dye (yellow) and signals 3–5 from Rhodamine 590 dye (red). An image of the total range is shown to the right of the spectrum, and compared with an overlay of the images 1–5. Note that all data shown in this figure were taken in one measurement.

## Status

- First PI<sub>m</sub>MS1 sensors were received in November 2010
- Initial Characterisation and commissioning performed in Early 2011
- First experiments in a Mass Spectrometer in April 2011
- Sensor calibration was completed July 2011
- PI<sub>m</sub>MS2 sensors received September 2012, characterisation is in progress.